

## Pressure dependence of high- $T_c$ superconductors

R. Griessen

*Natuurkundig Laboratorium der Vrije Universiteit, Amsterdam, The Netherlands*

(Received 10 July 1987)

The pressure dependence of the transition temperature of high- $T_c$  superconductors is considered within the framework of the standard Bardeen-Cooper-Schrieffer (BCS) electron-phonon theory, the bidimensional BCS theory, the resonating-valence-bond theories, and various bipolaronic superconductivity models.

### I. INTRODUCTION

High- $T_c$  superconductivity has been reported to occur in Ba-La-Cu-O, La-Sr-Cu-O, Y-Ba-Cu-O, and other compounds involving rare earths.<sup>1,2</sup> Already in the early stage of research on these perovskitelike compounds Chu *et al.*<sup>3</sup> demonstrated that in Ba-La-Cu-O the critical temperature could be increased drastically under pressure. The value  $dT_c/dp = 0.64$  K (kbar)<sup>-1</sup> was the highest pressure derivative ever observed in a superconductor. In sharp contrast to Ba-La-Cu-O, the Y-Ba-Cu-O system exhibits only a very weak increase of the onset temperature  $T_{co}$  with increasing pressure. In the low-pressure regime up to 19 kbar Hor *et al.*<sup>4</sup> found  $dT_{co}/dp = 0.05$  K (kbar)<sup>-1</sup>, and recently Driessen *et al.*<sup>5</sup> reported a value  $dT_{co}/dp = 0.043$  K (kbar)<sup>-1</sup> obtained from high-pressure experiments in a diamond-anvil cell up to 170 kbar.

Until now various mechanisms have been proposed to explain the remarkable behavior of high- $T_c$  superconductors under high pressure.

(i) Chu *et al.*<sup>3</sup> remarked that the large  $dT_c/dp$  of La-Ba-Cu-O is consistent with the occurrence of interfacial superconductivity between a superconducting metal and a semiconductor. Pressure in that case acts as a continuous parameter with which it is possible to optimize the coupling between both constituents, the Fermi energy of the metal and the band gap of the semiconductor. Within this interpretation it is not clear why Y-Ba-Cu-O should be so different from La-Ba-Cu-O.

(ii) For  $\text{La}_{2-x}(\text{Ba},\text{Sr})_x\text{CuO}_4$  Weber<sup>6</sup> calculated the Eliashberg  $\alpha^2F(\omega)$  function by means of the non-orthogonal tight-binding theory of lattice dynamics. He showed that when lanthanum is partially substituted by a divalent metal (Ba or Sr) the static Peierls distortion discussed by Mattheiss<sup>7</sup> for  $\text{La}_2\text{CuO}_4$  disappears and that giant Kohn anomalies exist near the Brillouin-zone boundary for oxygen breathing modes. The stability of the Peierls distortion depends on the force constant  $f_2$  of the planar Cu—O bond. For a superconductor with, for example,  $x = 0.2$  the results of Fig. 3 in Ref. 6 imply that  $d\ln T_c/d\ln f_2 = -4.4$ . Under pressure  $f_2$  is expected to increase. Unfortunately, the Grüneisen parameter corresponding to modes determined by  $f_2$  have not been determined yet. For an estimate we use the high-pressure results of Sugiura and Yamada<sup>8</sup> on  $\text{BaBiO}_3$ . They found from Raman scattering experiments at pressures up to 180 kbar that the stretching mode frequency  $\omega$  of the  $\text{BiO}_6$  octahedra varies linearly with volume, so that

$d\ln\omega/d\ln V = -1.4$ . For  $f_2$  in Ba-La-Cu-O one thus expects similarly  $d\ln f_2/d\ln V \cong -2.8$  as  $f_2 \propto \omega^2$ . With a compressibility of  $6 \times 10^{-7}$  bar<sup>-1</sup> we find finally that  $d\ln T_c/dp \cong -7.4 \times 10^{-3}$  (kbar)<sup>-1</sup> which, for  $T_c = 32$  K, leads to  $dT_c/dp \cong -0.24$  K (kbar)<sup>-1</sup>. This is too small in magnitude, and furthermore, it has the *wrong* sign. Within the normal band-structure electron-phonon interaction formalism it is thus not possible to understand the large increase of  $T_c$  with pressure.

Weber suggested, however, that  $dT_c/dp$  might be large for *inhomogeneous* samples, e.g., samples in which spinodal decomposition waves lead to spatial fluctuations in  $x$ . An increase in  $f_2$  under pressure pushes the Peierls instability to smaller values of  $x$  where higher electron-phonon enhancement factors  $\lambda$  are possible without destroying the lattice stability. As follows from the lattice stability line in Fig. 3 of Ref. 6,  $T_c$  increases on this line approximately as  $d\ln T_c/d\ln f_2 = 1.5$ . Using the same estimates as above one then obtains  $dT_c/dp \cong 0.08$  K (kbar)<sup>-1</sup>. Thus even if one assumes that under pressure regions of the sample with Ba (or Sr) concentrations smaller than the nominal concentration become superconducting because of an increase in  $f_2$  with pressure, one still obtains values for  $dT_c/dp$  which are almost one order of magnitude smaller than found experimentally. Furthermore, as pointed out in Ref. 5, the spatial concentration fluctuations required to explain a large and positive  $dT_c/dp$  would lead to a considerable smearing out of the transition and, in particular, to a lowering of the midpoint transition with increasing pressure, in sharp contrast to the experimental data.<sup>3</sup>

(iii) Hor *et al.*<sup>4</sup> suggested that the weak pressure dependence of  $T_c$  for Y-Ba-Cu-O might be due to the “chemical” pressure already present due to the replacement of La by Y. To check the validity of this argument we use the recent structure studies of Capponi *et al.*,<sup>9</sup> and Beno *et al.*<sup>10</sup> for  $\text{YBa}_2\text{Cu}_3\text{O}_7$  and Jorgensen *et al.*<sup>11</sup> for  $\text{La}_{1.85}\text{Ba}_{0.15}\text{CuO}_4$ . In  $\text{YBa}_2\text{Cu}_3\text{O}_7$  the four nearest oxygen neighbors are at an average distance of 1.92 Å from a copper atom. In  $\text{La}_{1.85}\text{Ba}_{0.15}\text{CuO}_4$  there are four oxygen atoms at a distance of 1.90 Å. On the basis of this argument one would therefore conclude that the Cu—O bonds are rather insensitive to the “chemical” pressure mentioned by Hor *et al.*<sup>4</sup>

On the other hand, if one simply considers that the average volume per atom,  $\Omega = 13.3$  Å<sup>3</sup> for  $\text{YBa}_2\text{Cu}_3\text{O}_7$ , is significantly smaller than  $\Omega = 27.2$  Å<sup>3</sup> for  $\text{La}_{1.85}\text{Ba}_{0.15}\text{CuO}_4$  or  $\Omega = 26.9$  Å<sup>3</sup> for  $\text{La}_{1.85}\text{Sr}_{0.15}\text{CuO}_4$ ,  $\text{YBa}_2\text{Cu}_3\text{O}_7$  may then be considered as a “compressed” Ba-La-Cu-O,

TABLE I. Pressure and volume dependence of the onset temperature  $T_{co}$ , the midpoint temperature  $T_c$ , and the temperature  $T_{cf}$  at which the transition is completed. For the conversion of pressure derivatives to volume derivatives we used  $B = 1600$  kbar for the bulk modulus of La-Ba-Cu-O and La-Sr-Cu-O and  $B = 1700$  kbar for Y-Ba-Cu-O. The pressure range for each experiment is indicated in the column  $p$ . The symbols in the last column are used in Fig. 1.

Sample	$T_{co}$ (K)	$T_c$ (K)	$T_{cf}$ (K)	$p$ (kbar)	$dT_c/dp$ (K/kbar)	$d \ln T_c / dp$ ( $10^{-2}$ kbar $^{-1}$ )	$\frac{d \ln T_c}{d \ln V}$	Symbol, Ref.
La <sub>1.25</sub> Sr <sub>0.15</sub> CuO <sub>4-y</sub>		36		$\leq 10$	0.28	7.78	-12.4	$\Delta$ , 15
La <sub>1.8</sub> Sr <sub>0.2</sub> CuO <sub>4-y</sub>	37			$\leq 20$	0.12	0.32	-5.2	$\Delta$ , 16
	37				0.32	0.87	-13.9	$\Delta$ , 16
La <sub>2</sub> CuO <sub>4</sub>	$\approx 40$			$\leq 10$	1.05	2.63	-42	$\circ$ , 17
La <sub>0.8</sub> Ba <sub>0.2</sub> CuO <sub>3-y</sub>	32			$\leq 17$	0.64	2.00	-32.0	$\bullet$ , 3
La <sub>1.85</sub> Ba <sub>0.15</sub> CuO <sub>4-y</sub>	35.2			$\leq 19$	0.32	0.90	-14.5	$\bullet$ , 18
		30.4			0.17	0.56	-8.9	$\bullet$ , 18
			26.0		0.13	0.50	-8.0	$\bullet$ , 18
Y <sub>0.325</sub> Ba <sub>0.675</sub> CuO <sub>2.3</sub>	92			$\leq 10$	0.17	0.19	-3.1	$\square$ , 19
			84		0.40	0.48	-8.1	$\square$ , 19
Y <sub>0.35</sub> Ba <sub>0.65</sub> CuO <sub>2.3</sub>	93			$\leq 10$	0.10	0.11	-1.8	$\square$ , 19
			79.5		0.20	0.25	-4.3	$\square$ , 19
Y <sub>0.425</sub> Ba <sub>0.575</sub> CuO <sub>2.3</sub>	93.5			$\leq 10$	0.09	0.01	-1.6	$\square$ , 19
			83.6		0.28	0.34	-5.7	$\square$ , 19
Y <sub>0.4</sub> Ba <sub>0.6</sub> CuO <sub>3-y</sub>		89.7		$\leq 9.5$	-0.25	-0.28	4.7	$\nabla$ , 20
YBa <sub>2</sub> Cu <sub>3</sub> O <sub>7</sub>	90			$\leq 18$	$\sim 0$	$\sim 0$	$\sim 0$	$\nabla$ , 21
		87			$\sim 0$	$\sim 0$	$\sim 0$	$\nabla$ , 21
			85		$\sim -0.30$	$\sim -0.35$	$\sim 6.0$	$\nabla$ , 21
(Y <sub>0.6</sub> Ba <sub>0.4</sub> ) <sub>2</sub> CuO <sub>4-s</sub>	91.5			$\leq 19$	0.114	0.13	-2.1	$\nabla$ , 4
			88.5		-0.079	0.09	1.5	$\nabla$ , 4
YBa <sub>2</sub> Cu <sub>3</sub> O <sub>7</sub>	91			$\leq 170$	0.043	0.047	-0.80	$\otimes$ , 5
			88		-0.070	0.080	1.35	$\otimes$ , 5
Y <sub>1.2</sub> Ba <sub>1.8</sub> Cu <sub>3</sub> O <sub>6.6</sub>	92			$\leq 120$	0.045	0.049	-0.83	$\times$ , 22
			87		-0.060	0.069	1.17	$\times$ , 22

although the value of such reasoning is highly questionable.

From the foregoing it is quite clear that a coherent description of the pressure dependence of  $T_c$  in metal oxide is still lacking. In this work we *assume* that the observed properties of high- $T_c$  superconductors are *bulk* properties and show that the normal BCS approach cannot account for the various  $dT_c/dp$  values measured so far for superconducting metal oxides. To simplify the comparison of theory and experiment it is useful first to convert the pressure derivatives  $dT_c/dp$  into relative volume derivatives  $d \ln T_c / d \ln V$ . From the measurements of Salomons *et al.*<sup>12</sup> we estimate that the bulk modulus of YBa<sub>2</sub>Cu<sub>3</sub>O<sub>7.1</sub> is  $B \approx 1700$  kbar. From the pressure data of Driessen *et al.*<sup>5</sup> and Hor *et al.*<sup>4</sup> it then follows that

$$\frac{d \ln T_c}{d \ln V} \approx -0.8, \quad (1)$$

and from the data of Chu *et al.* for YBa<sub>2</sub>Cu<sub>3</sub>O<sub>7.1</sub> that

$$\frac{d \ln T_c}{d \ln V} \approx -32 \quad (2)$$

if one uses the same bulk modulus value for Ba-La-Cu-O as that measured by Takahashi *et al.*<sup>13</sup> and Terada *et al.*<sup>14</sup> ( $B \approx 1600$  kbar).

Very recently Allgeier *et al.*<sup>15</sup> reported that for La<sub>1.85</sub>-Sr<sub>0.15</sub>CuO<sub>4</sub>  $T_c$  also increases rapidly with pressure ( $p < 10$

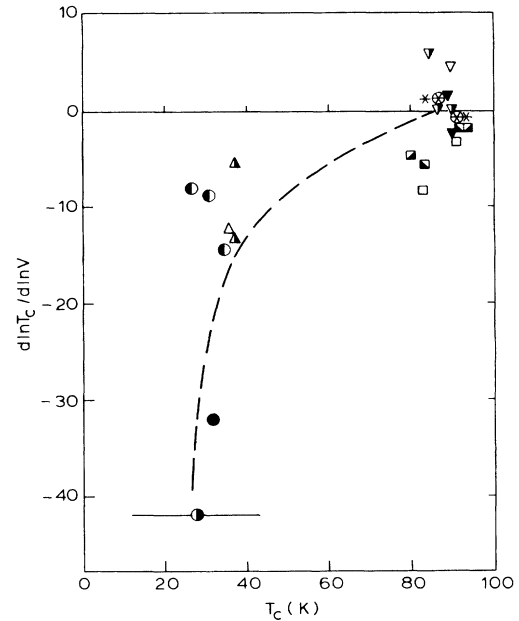


FIG. 1. Relative volume dependence of  $T_c$  as a function of  $T_c$ . The symbols are defined in Table I. The error bar for La<sub>2</sub>CuO<sub>4</sub> reflects the uncertainty in defining a midpoint transition temperature for this oxide (Ref. 17). The large scatter of points for Y-Ba-Cu-O ( $T_c > 80$  K) is probably due to the use of polyphased samples in the earlier investigations.

kbar) at the rate of  $dT_c/dp = 0.28 \text{ K (kbar)}^{-1}$ . With  $T_c = 36 \text{ K}$  and  $B \cong 1600 \text{ kbar}$  we then obtain

$$\frac{d \ln T_c}{d \ln V} = -12.4. \quad (3)$$

More experimental values are given in Table I. Quite impressive is the good agreement between the measurements of Okai, Takahashi, and Ohta<sup>22</sup> and Driessen *et al.*<sup>5</sup> on Y-Ba-Cu-O in the high-pressure regime. The data in Table I also exhibit a general trend for  $d \ln T_c / d \ln V$ . For the superconductors with the highest  $T_c$  the volume dependence of the transition temperature is especially weak. This is clearly shown in Fig. 1.

## II. BCS THEORY WITH ELECTRON-PHONON INTERACTION

For the discussion of the volume dependence of  $T_c$  within the standard BCS model we start from the expression of Allen and Dynes<sup>23</sup>

$$T_c = \frac{\Theta_{\log} f_1 f_2}{1.2} \exp \left[ -\frac{1.04(1+\lambda)}{\lambda - \mu^*(1+0.62\lambda)} \right], \quad (4)$$

with

$$f_1 = \{1 + [\lambda/(2.46 + 9.35\mu^*)]^{3/2}\}^{1/3}, \quad (5)$$

$$f_2 = 1 + \frac{(\bar{\omega}_2/\omega_{\log} - 1)\lambda^2}{\lambda^2 + (1.82 + 11.5\mu^*)^2 \bar{\omega}_2^2/\omega_{\log}^2}, \quad (6)$$

$$g(\lambda, \mu^*) = \frac{1.04(1+0.38\mu^*)\lambda}{[\lambda - \mu^*(1+0.62\lambda)]^2} + \frac{\lambda^{3/2}}{2[\lambda^{3/2} + (2.46 + 9.35\mu^*)^{3/2}]}, \quad (12)$$

and

$$\gamma_{\log} \equiv -d \ln \Theta_{\log} / d \ln V.$$

If for  $\mu^*$  we choose the canonical value 0.13 the function  $g(\lambda)$  is well approximated by the following simple expression

$$g(\lambda) \cong 0.4 + (1/\lambda) \quad (13)$$

in the range  $1.5 \leq \lambda \leq 10$  relevant to high- $T_c$  superconductors. From Eqs. (11) and (13) then directly follows that a volume derivative as large as that observed in Ba-La-Cu-O [Eq. (2)] is not possible within the standard electron-phonon BCS theory unless unrealistically large Grüneisen parameters or strongly volume-dependent electron-phonon enhancement parameters are assumed. To be more specific we express  $\lambda$  in terms of the electronic electron-phonon interaction parameter  $\eta$  and the phononic part  $M(\omega^2)$ . We have then

$$\frac{d \ln \lambda}{d \ln V} = \frac{d \ln \eta}{d \ln V} + 2\langle \gamma \rangle \quad (14)$$

with

$$\langle \gamma \rangle \equiv -\frac{d \ln (\langle \omega^2 \rangle^{1/2})}{d \ln V} \quad (15)$$

as  $\lambda = \eta/M(\omega^2)$ . As  $\langle \gamma \rangle \cong \gamma_{\log}$  it follows from Eqs. (11),

with

$$\omega_{\log} \equiv \exp \left[ \frac{2}{\lambda} \int_0^\infty \frac{\ln \omega}{\omega} \alpha^2 F(\omega) d\omega \right], \quad (7)$$

and

$$\bar{\omega}_2 = \left[ \int_0^\infty \omega \alpha^2 F(\omega) d\omega / \left[ \int_0^\infty \frac{\alpha^2 F(\omega)}{\omega} d\omega \right] \right]^{1/2}. \quad (8)$$

$\mu^*$  is the conventional Coulomb pseudopotential,  $\lambda$  the electron-phonon enhancement parameter,  $\Theta_{\log} \equiv \hbar \omega_{\log} / k_B$ , and  $\alpha^2 F(\omega)$  the Eliashberg function.  $\lambda$  and  $\alpha^2 F(\omega)$  are related to each other by

$$\lambda = 2 \int_0^\infty \frac{\alpha^2 F(\omega) d\omega}{\omega}. \quad (9)$$

The Eliashberg function has not been calculated for the high- $T_c$  superconductors (except  $\text{La}_2\text{CuO}_4$ ) until now. From numerical examples we conclude, however, that  $\bar{\omega}_2 \cong \omega_{\log}$  and that  $f_2 \cong 1$ . For simplicity we set  $f_2 = 1$ . We also assume that  $\mu^*$  is volume independent. The critical temperature is then given by an expression of the form

$$T_c = \Theta_{\log} f(\lambda, \mu^*) \quad (10)$$

and its volume derivation can be written

$$\frac{d \ln T_c}{d \ln V} = -\gamma_{\log} + g(\lambda, \mu^*) \frac{d \ln \lambda}{d \ln V} \quad (11)$$

with

(13), and (14) that for large  $\lambda$

$$\frac{d \ln T_c}{d \ln V} \cong 0.5 \frac{d \ln \eta}{d \ln V}. \quad (16)$$

For many superconductors<sup>24</sup>  $d \ln \eta / d \ln V \cong -2$ , so that  $d \ln T_c / d \ln V \cong -1$ , which is much smaller than the values given in Eqs. (1)–(3) or Table I.

## III. BIDIMENSIONAL BCS MODEL

Recently Labbé and Bok<sup>25</sup> presented a model for the superconductivity of a nearly half-filled two-dimensional lattice. Because of the bidimensional character the electronic density of states  $n(E)$  has a logarithmic divergence at the energy  $E_s$  corresponding to an exactly half-filled band. Near  $E_s$ ,

$$n(E) = \frac{N}{\pi^2 D} \ln \left[ \frac{D}{|E - E_s|} \right], \quad (17)$$

where  $D$  is the “width” of the singularity given by

$$D = \frac{\gamma^2}{[(E_d - E_p)^2 + 16\gamma^2]^{1/2}}, \quad (18)$$

where  $\gamma$  is the transfer integral between  $d_{x^2-y^2}$  and  $p_x$  or-

bitals and  $N$  is the number of unit cells. In Eq. (18)  $E_d - E_p$  is the difference between the energy of copper 3d and oxygen 2p states. By assuming that  $E_F$  coincides with  $E_s$ , Labbé and Bok obtained the following expression for  $T_c$ , in the weak-coupling limit

$$k_B T_c = 1.13 \hbar D \exp[(-1/\sqrt{\lambda})] . \quad (19)$$

This relation shows explicitly that the cutoff energy of interest is determined by the width of the logarithmic van Hove singularity and not by the phonon frequency. For the volume dependence of  $T_c$  one finds by simple differentiation of Eq. (19) that

$$\frac{d \ln T_c}{d \ln V} = \frac{d \ln D}{d \ln V} + \frac{1}{2\sqrt{\lambda}} \frac{d \ln \lambda}{d \ln V} . \quad (20)$$

From Eq. (18) it follows that  $d \ln D / d \ln V \approx d \ln t_b / d \ln V \approx -1$  if the volume dependence of  $E_d - E_p$  is neglected. To calculate the contribution of the second term in Eq. (20) we need to evaluate  $\lambda$ . As the width  $W_b$  of the band is  $W_b = 8t_b$ , we estimate from the band-structure calculations of Mattheiss,<sup>7</sup> Oguchi,<sup>26</sup> and Yu, Freeman, and Xu<sup>27</sup> that  $\gamma \approx 1.4$  eV,  $D \approx 0.3$  eV, and, consequently,  $\sqrt{\lambda} \approx 0.27$  corresponds to  $T_c = 95$  and  $\sqrt{\lambda} \approx 0.21$  to  $T_c = 32$  K (Ba-La-Cu-O).

In Fig. 2 we indicate how  $d \ln T_c / d \ln V$  varies with  $T_c$  for two different cases: (i) with  $d \ln D / d \ln V = -1$ ,  $d \ln \lambda / d \ln V = -2$ , and  $D = 0.3$  eV; and (ii) with  $d \ln D / d \ln V = 4$ ,  $d \ln \lambda / d \ln V = -3$ , and  $D = 0.3$  eV. This second case is chosen to show that the trend in Fig. 1 may be qualitatively reproduced by means of a two-dimensional (2D) BCS theory. The assumed positive value of  $d \ln D / d \ln V$  implies, however, that  $E_d - E_p$  is strongly volume dependent. Band-structure calculations at various volumes would be required to clarify this assumption.

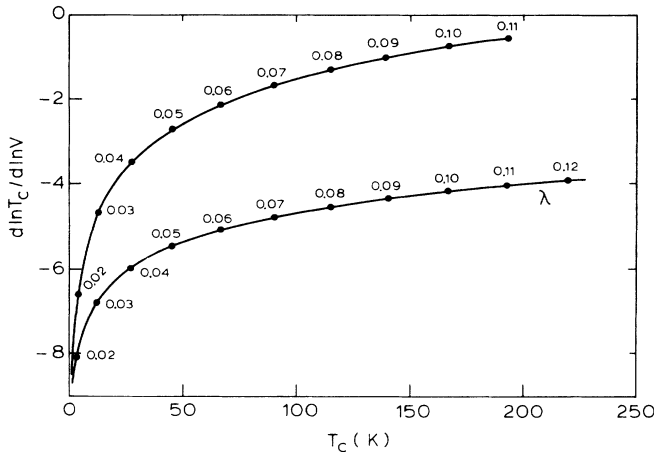


FIG. 2. Relative volume dependence of  $T_c$  as a function of  $T_c$  according to the Labbé and Bok model.  $T_c$  is calculated by means of Eq. (19) with  $D = 0.3$  eV for the width of the logarithmic singularity in the density of states at  $E_F$ . The volume derivatives  $d \ln T_c / d \ln V$  are obtained from Eq. (20) with  $d \ln \lambda / d \ln V = -2$  and  $d \ln D / d \ln V = -1$  (—) and  $d \ln \lambda / d \ln V = -3$  and  $d \ln D / d \ln V = 4$  (---). The values indicated correspond to  $\lambda$ .

To conclude this subsection on standard BCS theory (with electron-phonon coupling) it is worth mentioning that from the magnetic-susceptibility measurements of Allgeier *et al.*<sup>15</sup> it follows that  $|d \ln N(E_F) / d \ln V| \gtrsim 3$  in  $\text{La}_{1.85}\text{Sr}_{0.15}\text{CuO}_4$ . The large  $d \ln \lambda / d \ln V$  which would be required within the 2D or 3D BCS theory to explain the high  $d \ln T_c / d \ln V$  would therefore imply very large volume dependence of the effective attractive interaction  $V_{\text{el-ph}}$  as  $\lambda = N(E_F) V_{\text{el-ph}}$ .

#### IV. RESONATING-VALENCE BONDS

From structural information on  $\text{La}_2\text{CuO}_4$  Anderson<sup>28</sup> concluded that the  $\text{Cu}^{2+}$  ions were in an  $S = \frac{1}{2}$  singlet state, strongly hybridized with the  $p$  levels of the nearest oxygen atoms. On the basis of an earlier article<sup>29</sup> he proposed that, certainly for the two-dimensional triangular antiferromagnet with  $S = \frac{1}{2}$ , and probably for other lattices, the ground state might be the analog of the precise singlet in Bethe's solution of the one-dimensional antiferromagnetic chain.<sup>30</sup> Both for the linear chain and the triangular lattice he showed that a state consisting only of nearest-neighbor singlet pairs is more realistic than the regular spin-up, spin-down arrangement of the Néel state. Further lowering of the ground-state energy is obtained by allowing the singlet pairs to tunnel through the lattice. These qualitative statements are supported by the numerical simulations of Hirsch<sup>31</sup> for the 2D square-lattice Hubbard model with various band fillings.

For the resonating-valence-bond models in the strong-coupling limit ( $t_b^2 < U$ ) Anderson<sup>28</sup> proposes that  $T_c \lesssim t_b^2 / U$ , where  $t_b$  is the single-electron hopping integral for the noninteracting system ( $U = 0$ ).  $U$  is the local electron-electron repulsion for electrons of opposite spins in the same atomic orbital. For a two-dimensional square lattice the width  $W_b$  of the electronic band is  $W_b = 8t_b$ . For the volume dependence of  $T_c$  it then follows that

$$\frac{d \ln T_c}{d \ln V} = 2 \frac{d \ln W_b}{d \ln V} - \frac{d \ln U}{d \ln V} . \quad (21)$$

For pure  $d$  bands,<sup>32</sup>  $d \ln W_b / d \ln V = -\frac{5}{3}$  and for free electrons  $d \ln W_b / d \ln V = -\frac{2}{3}$ . For most pure metals the electronic Grüneisen parameter<sup>33</sup>  $\gamma_e \equiv [d \ln N(E_F)] / d \ln V \approx -d \ln W_b / d \ln V$  varies between 0.2 and 2. For the present discussion we take  $d \ln W_b / d \ln V \approx -1$ .  $U$  being essentially an intrasite parameter, we expect that  $d \ln U / d \ln V \approx 0$  so that, typically,  $d \ln T_c / d \ln V \approx -2$ .

As for the standard BCS theory with (strong) electron-phonon interaction, we see that the resonating-valence-bond model (in the form presented above) is not able to reproduce the large  $d \ln T_c / d \ln V \approx -32$  observed in Ba-La-Cu-O.

In a recent paper Fukuyama and Yosida<sup>34</sup> explored some implications of the mechanism proposed by Anderson.<sup>28</sup> Starting from the nondegenerate Hubbard model

$$H = \sum_{ij} t_{ij} a_{i\sigma}^\dagger a_{j\sigma} + U \sum_i n_{i\uparrow} n_{i\downarrow} \quad (22)$$

with the transfer integral  $t_b$  between nearest neighbors,

they find in the limit  $U \gg t_b$  that  $T_c$  is given by

$$k_B T_c = 1.13 \hbar \omega_0 \exp \left[ -\frac{1}{\lambda(n)} \right] \quad (23)$$

with

$$\lambda(n) = \frac{8}{\pi} \frac{t_b}{U} \Phi(n), \quad (24)$$

where  $\Phi(n)$  depends only on the electron density per site,  $n=1$  corresponding to the case of a half-filled band. The cutoff energy  $\hbar \omega_0$  is of the order of  $t_b$ . From Eqs. (23) and (24) it then follows that

$$\frac{d \ln T_c}{d \ln V} \cong \frac{d \ln t_b}{d \ln V} \left[ 1 + \frac{1}{\lambda(n)} \right] \quad (25)$$

if, as before,  $d \ln U / d \ln V$  is taken to be zero. With  $\hbar \omega_0 = 0.2 t_b = 0.08$  eV (Refs. 7, 26, and 27) we find from Eq. (23) that  $\lambda \cong 0.4$  corresponds to  $T_c = 95$  K and  $\lambda \cong 0.3$  to  $T_c = 32$  K for a nearly half-filled band ( $n=0.9$ ). In this version of the resonance-valence-bond model we thus see that moderately high values for  $d \ln T_c / d \ln V$  are possible ( $-3, \dots, -8$ ). The values of  $\lambda$  mentioned above (0.3, 0.4) imply, however, that  $t_b \approx U$ . The use of the effective Hubbard Hamiltonian derived by Hirsch<sup>31</sup> for the case  $t_b \ll U$  is therefore questionable.

Using the approach he proposed in the context of heavy-electron systems, Cyrot<sup>35</sup> obtained the following expression for  $T_c$ :

$$T_c \approx t_b \delta \exp(-U \delta / t_b), \quad (26)$$

where  $\delta$  is the fractional doping which creates some  $\text{Cu}^{3+}$  ions instead of  $\text{Cu}^{2+}$ . This expression for  $T_c$  has a maximum for  $\delta = t_b / U$ . For this value  $T_c = t_b^2 / U$  as predicted by Anderson for his resonating-valence-band model.

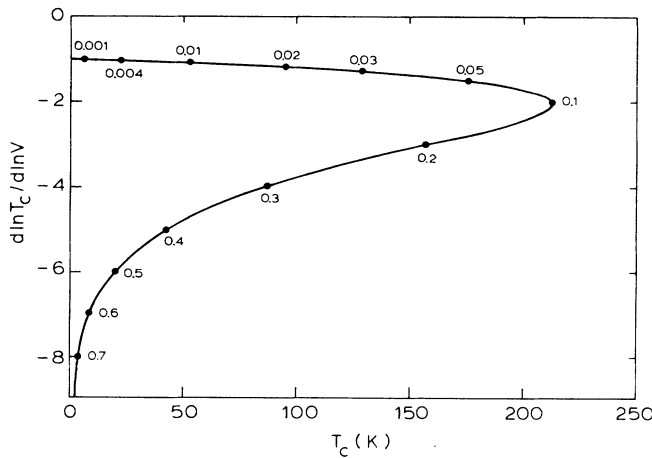


FIG. 3. Relative volume dependence of  $T_c$  as a function of  $T_c$  according to the model of Cyrot.  $T_c$  is calculated by means of Eq. (26) with  $t_b = 0.5$  eV and  $U = 5$  eV. The corresponding  $d \ln T_c / d \ln V$  are obtained from Eq. (27) with  $d \ln t_b / d \ln V = -1$ . The values indicated correspond to the fractional doping  $\delta$ .

From Eq. (26) it follows that

$$\frac{d \ln T_c}{d \ln V} = \frac{d \ln t_b}{d \ln V} \left[ 1 + \frac{U \delta}{t_b} \right]. \quad (27)$$

In Fig. 3 we represent  $d \ln T_c / d \ln V$  as a function of  $T_c$  for the case  $t_b = 0.5$  eV,  $U = 5$  eV, and  $d \ln t_b / d \ln V = -1$ . For fractional doping  $\delta > 0.1$ ,  $d \ln T_c / d \ln V$  becomes more and more negative while  $T_c$  decreases. This behavior is in qualitative agreement with the experimental data shown in Fig. 1.

## V. MANY-POLARONIC SUPERCONDUCTIVITY

Before discussing bi- or many-polaronic superconductivity it is useful to determine which values of the electron-phonon enhancement parameter  $\lambda$  are required to reproduce  $T_c \geq 35$  K within the framework of the standard strong-coupling BCS theory.<sup>23</sup>

We consider first Ba-La-Cu-O for which Weber<sup>6</sup> has made quantitative calculations of  $\lambda$ . From Fig. 3 in Ref. 6 it follows that  $T_c = 35$  K for  $\lambda = 2.5$  and a planar Cu—O band-stretching force constant  $f_2 = 11$  eV/Å<sup>2</sup>. The corresponding  $\Theta_{\log}$  determined from Eq. (3) by setting  $T_c = 35$  K,  $\lambda = 2.5$ , and  $\mu^* = 0.13$  is  $\Theta_{\log} = 194$  K. To obtain  $T_c = 95$  K with the same  $\Theta_{\log}$  we would need  $\lambda = 13.5$ . Even with a significant higher  $\Theta_{\log}$ , say  $\Theta_{\log} = 400$  K, we still need  $\lambda = 3.75$ . As discussed by Cyrot,<sup>35</sup> Chakraverty,<sup>36</sup> Anderson and Cohen,<sup>37</sup> Rice and Sneddon,<sup>38</sup> Alexandrov and co-workers,<sup>39,40</sup> and Nasu<sup>41</sup> in the limit of large electron-phonon coupling bipolaron formation may occur. The condition for bipolaron formation is essentially the same as that for strong coupling in the standard BCS theory,  $\lambda > 1$ , i.e.,

$$\frac{2zg^2\hbar\omega}{W_b} > 1, \quad (28)$$

where  $W_b$  is the width of the *bare* (i.e., unrenormalized) electron band,  $z$  the number of nearest neighbors in the lattice under investigation,  $\omega$  a characteristic phonon frequency, and  $g$  a dimensionless parameter characterizing the strength of the electron-phonon interaction defined as

$$g^2 \equiv \sum_{\mathbf{q}} \frac{|U(\mathbf{q})|^2 [1 - \cos(\mathbf{q}(\mathbf{R}_m - \mathbf{R}_{m'}))]}{\hbar^2 \omega_{\mathbf{q}}^2}, \quad (29)$$

where  $U(\mathbf{q})$  is the Fourier transform of the electron-lattice interaction and  $\mathbf{R}_m$  is the position of the  $m$ th sites. For a square density of states  $W_b = 1/N(E_F)$ , where  $N(E_F)$  is the *bare* electronic density of states at the Fermi energy and Eq. (28) can be written in the usual form:

$$\bar{V}N(E_F) > 1, \quad (30)$$

with  $V = 2zg^2\hbar\omega$  as the phonon-mediated attractive interaction. Starting from the usual Fröhlich interaction, Alexandrov, Ranninger, and Robaskiewicz<sup>40</sup> derived the following equation for the superconducting  $T_c$ :

$$\frac{1}{2n_b - 1} = \frac{1}{N} \sum_{\mathbf{k}} \coth \left[ \frac{(2n_b - 1)}{2k_B T_c} (t - t_{\mathbf{k}}) \right], \quad (31)$$

where  $n_b$  is the concentration of bipolarons,  $N$  the number

of sites in the lattice, and

$$t = \frac{2zt_b^2}{\Delta} \exp(-2g^2), \quad (32)$$

$$t_{\mathbf{k}} = \frac{t}{z} \sum_{\mathbf{R}_m} e^{i\mathbf{k} \cdot \mathbf{R}_m}, \quad (33)$$

$$\Delta \approx 2g^2 \hbar \omega - V_0, \quad (34)$$

where  $t_b$  is the bare electron hopping integral ( $W_b = 8t_b$  for a square lattice) and  $V_0$  the Coulomb repulsion. Equation (32) pertains to the case where  $k_B T_c < \Delta < \hbar \omega$ . (For the case  $\hbar \omega \ll \Delta$ , see Ref. 5.)

Without solving Eq. (31) we obtain, by differentiating with respect to volume, both sides of Eq. (31),

$$\frac{d \ln T_c}{d \ln V} = \frac{d \ln t}{d \ln V} = 2 \frac{d \ln t_b}{d \ln V} - \frac{d \ln \Delta}{d \ln V} - 2g^2 \frac{d \ln g^2}{d \ln V} \quad (35)$$

if one neglects the volume dependence of  $V_0$ . Equation (35) leads to

$$\frac{d \ln T_c}{d \ln V} = 2 \frac{d \ln W_b}{d \ln V} + \frac{\gamma}{1 - v_0} - \left( 2g^2 + \frac{1}{1 - v_0} \right) \frac{d \ln g^2}{d \ln V}, \quad (36)$$

where  $\gamma \equiv -d \ln \omega / d \ln V$  and  $v_0 \equiv V_0 / (2\hbar \omega g^2)$  is the ratio of the Coulomb repulsion to the polaronic level shift  $2\hbar \omega g^2$ . As bipolaron formation is required for the existence of superconductivity we have necessarily  $v_0 < 1$ . One interesting feature of Eq. (36) is that it may lead to large volume derivatives for  $T_c$ . To illustrate this point we note that the set of parameters  $z = 4$ ,  $g^2 = 4$ ,  $\hbar \omega = 74$  meV (corresponding to a Cu—O stretch bond<sup>6</sup> of 600 cm<sup>-1</sup>),  $W_b = 2.4$  eV, and  $V_0 = 0.54$  eV satisfy Eq. (28) and the condition  $k_B T_c < \Delta < \hbar \omega$  as  $\Delta = 52$  meV. We have  $T_c \approx 0.3t = 28$  K (see Fig. 4 in Ref. 40) and

$$\frac{d \ln T_c}{d \ln V} \approx 2 \frac{d \ln W_b}{d \ln V} + 11\gamma - 19 \frac{d \ln g^2}{d \ln V}. \quad (37)$$

With  $d \ln g^2 / d \ln V = 2$ ,  $\gamma = 1$ , and  $d \ln W_b / d \ln V = -1$  one then obtains, for example,  $d \ln T_c / d \ln V = -31$ . For this example, the bipolaron binding energy  $\Delta$  is larger than the renormalized polaronic half-band width

$$W_p = \frac{W_b}{2} \exp(-g^2), \quad (38)$$

which is equal to 22 meV. In this regime of strong polaron-polaron coupling, local small bipolarons occur. As the value assumed for the Coulomb repulsion is relatively small the bipolarons are probably involving polarons on adjacent atoms rather than polarons located on the same atom.<sup>40</sup>

Micnas, Ranninger, and Robaskiewicz<sup>42</sup> proposed recently an extension of their bipolaronic theory of superconductivity. In order to investigate the formation of electron pairs in the regime of moderately strong electron-lattice coupling they consider a system consisting of a mixture of wide- and narrow-band electrons. The narrow-band electrons are able to induce a strong polarization of the surrounding ligands, which in turn leads to

the formation of local bipolarons. The hybridization of these narrow-band electrons with the wide-band electrons provides a new mechanism for superconductivity in which the local pair formation leads to quasibosons and the itinerant electrons play the role of Cooper pairs. Micnas *et al.*<sup>42</sup> expect that the maximum value for  $T_c$  is obtained when the concentration of both types of electrons is roughly equal. Then

$$k_B T_c \sim \hbar \frac{I^2}{W_w}, \quad (39)$$

where  $I$  is the hybridization coupling between the two bands and  $W_w$  is the width of the wide band. As  $I \sim \exp(-2g^2)$  we find for the volume dependence of  $T_c$

$$\frac{d \ln T_c}{d \ln V} \approx -4g^2 \frac{d \ln g^2}{d \ln V} - \frac{d \ln W_w}{d \ln V}. \quad (40)$$

In the intermediate electron-lattice coupling regime one expects  $g^2 \approx 2$ , so that with  $d \ln g^2 / d \ln V = 2$  and  $d \ln W_w / d \ln V = -1$  again relatively large values of  $d \ln T_c / d \ln V$  are possible ( $d \ln T_c / d \ln V = -15$ ).

## VI. CONCLUSIONS

The  $dT_c/dp$  data available until now for high- $T_c$  superconductors indicate that  $d \ln T_c / d \ln V$  assumes very large negative values for the "low" high- $T_c$  metal oxides La<sub>2</sub>CuO<sub>4</sub>, La-Sr-Cu-O, and La-Ba-Cu-O, while it is essentially zero for Y-Ba-Cu-O. Among the several theoretical models considered in this work only (i) the two-dimensional BCS model of Labbé and Bok,<sup>25</sup> (ii) the resonating-valence-bond-like models (as treated by Fukuyama and Yosida<sup>34</sup> and Cryot<sup>35</sup>), and (iii) the bipolaronic model of Alexandrov, Ranninger, and Robaskiewicz<sup>40</sup> are able to reproduce large values for  $d \ln T_c / d \ln V$  without having to assume unrealistically large values for  $d \ln \lambda / d \ln V$  or  $d \ln t_b / d \ln V$  for the electron-phonon enhancement parameter  $\lambda$  or the bare overlap integral  $t_b$ .

In the light of the recent measurements of the absence of isotope effect<sup>43,44</sup> in YBa<sub>2</sub>Cu<sub>3</sub>O<sub>7</sub> and EuBa<sub>2</sub>Cu<sub>3</sub>O<sub>7</sub> it is worthwhile to mention that the 2D BCS model may be weakly dependent on the isotope mass while any bipolaronic model is necessarily strongly isotope dependent. On the basis of the present analysis of  $dT_c/dp$  and of the absence of isotope effect one would thus favor the approach of Fukuyama and Yoshida or that of Cryot. However, both more experimental and theoretical work is clearly needed for an unambiguous identification of the mechanism responsible for high- $T_c$  superconductivity. We hope that the present work will stimulate theorists to discuss explicitly in the future the implications of their models for the volume dependence of  $T_c$ .

## ACKNOWLEDGMENTS

I am grateful to J. Ranninger and T. M. Rice for interesting discussion and to A. Driessen and H. Hemmes for their valuable contribution to the investigation of the pressure dependence of  $T_c$ .

- <sup>1</sup>P. H. Hor, R. L. Meng, Y. Q. Wang, L. Gao, Z. J. Huang, J. Bechtold, K. Forster, and C. W. Chu, *Phys. Rev. Lett.* **58**, 1891 (1987), and references therein.
- <sup>2</sup>D. W. Murphy, S. Sunshine, R. B. van Dover, R. J. Cava, B. Batlogg, S. M. Zahurak, and L. Schneemeyer, *Phys. Rev. Lett.* **58**, 1888 (1987).
- <sup>3</sup>C. W. Chu, P. H. Hor, R. L. Meng, L. Gao, Z. J. Huang, and Y. Q. Wang, *Phys. Rev. Lett.* **58**, 405 (1987).
- <sup>4</sup>P. H. Hor, L. Gao, R. L. Meng, Z. J. Huang, Y. Q. Wang, K. Forster, J. Vassiliou, C. W. Chu, M. K. Wu, J. R. Ashburn, and C. J. Torng, *Phys. Rev. Lett.* **58**, 911 (1987).
- <sup>5</sup>A. Driessen, R. Griessen, N. Koeman, E. Salomons, R. Brouwer, D. G. deGroot, K. Heeck, H. Hemmes, and J. Rector (unpublished).
- <sup>6</sup>W. Weber, *Phys. Rev. Lett.* **58**, 1371 (1987).
- <sup>7</sup>L. F. Mattheiss, *Phys. Rev. Lett.* **58**, 1028 (1987).
- <sup>8</sup>H. Sugiura and T. Yamadaya, *Physica* **139** & **140**, 349 (1986).
- <sup>9</sup>J. J. Capponi, C. Chaillout, A. W. Hewat, P. Lejay, M. Marezio, N. Nguyen, B. Raveau, J. L. Soubeyroux, J. L. Tholence, and R. Tournier, *Europhys. Lett.* (to be published).
- <sup>10</sup>M. A. Beno, L. Soderholm, D. W. Capone II, D. G. Hinks, J. D. Jorgensen, and I. K. Schuller, *Appl. Phys. Lett.* (to be published).
- <sup>11</sup>J. D. Jorgensen, H. B. Schüttler, D. G. Hinks, D. W. Capone II, K. Zhang, and M. B. Brodsky, *Phys. Rev. Lett.* **58**, 1024 (1987).
- <sup>12</sup>E. Salomons, H. Hemmes, J. J. Scholtz, N. Koeman, A. Driessen, D. G. de Groot, and R. Griessen (unpublished).
- <sup>13</sup>H. Takahashi, C. Murayama, S. Yomo, N. Mori, K. Kishio, K. Kitazawa, and K. Fueki, *Jpn. J. Appl. Phys.* **26**, L504 (1987).
- <sup>14</sup>N. Terada, H. Ihara, M. Hirabayashi, K. Senzaki, Y. Kimura, K. Murata, M. Tokumoto, O. Shimomura, and T. Kikegawa, *Jpn. J. Appl. Phys.* **26**, L510 (1987).
- <sup>15</sup>C. Allgeier, J. S. Schilling, H. C. Ku, P. Klazins, and R. N. Shelton (unpublished).
- <sup>16</sup>S. Yomo, C. Murayama, H. Takahashi, N. Mori, K. Kishio, K. Kitazawa, and K. Fueki, *Jpn. J. Appl. Phys.* **26**, L602 (1987).
- <sup>17</sup>P. M. Grant, S. S. P. Parkin, V. Y. Lee, E. M. Engler, M. L. Ramirez, J. E. Vazquez, G. Lim, R. D. Jacowitz, and R. L. Greene, *Phys. Rev. Lett.* **58**, 2482 (1987).
- <sup>18</sup>M. Kurisu, H. Kadomatsu, H. Fujiwara, Y. Maeno, and T. Fujita, *Jpn. J. Appl. Phys.* **26**, L361 (1987).
- <sup>19</sup>H. Yoshida, H. Morita, K. Noto, T. Kaneko, and H. Fujimori, *Jpn. J. Appl. Phys.* **26**, L867 (1987).
- <sup>20</sup>K. Murata, H. Ihara, M. Tokumoto, M. Hirabayashi, N. Terada, K. Senzaki, and Y. Kimura, *Jpn. J. Appl. Phys.* **26**, L471 (1987).
- <sup>21</sup>Y. Akahama, S. Endo, S. Noguchi, and K. Okuda, *Jpn. J. Appl. Phys.* **26**, L871 (1987).
- <sup>22</sup>B. Okai, K. Takahashi, and M. Ohta, *Jpn. J. Appl. Phys.* **26**, L820 (1987).
- <sup>23</sup>P. B. Allen and R. C. Dynes, *Phys. Rev. B* **12**, 905 (1975).
- <sup>24</sup>J. W. Garland and K. H. Bennemann, in *Superconductivity in d- and f-metals*, edited by D. H. Douglass (American Institute of Physics, New York, 1972), p. 255.
- <sup>25</sup>J. Labbé and J. Bok, *Europhys. Lett.* **3**, 1225 (1987).
- <sup>26</sup>T. Oguchi, *Jpn. J. Appl. Phys.* **26**, L417 (1987).
- <sup>27</sup>J. Yu, A. J. Freeman, and J. H. Xu, *Phys. Rev. Lett.* **58**, 1035 (1987).
- <sup>28</sup>P. W. Anderson, *Science* **235**, 1996 (1987).
- <sup>29</sup>P. W. Anderson, *Phys. Rev. Lett.* **34**, 953 (1975).
- <sup>30</sup>H. A. Bethe, *Z. Phys.* **71**, 205 (1931).
- <sup>31</sup>J. E. Hirsch, *Phys. Rev. B* **31**, 4403 (1985); *Phys. Rev. Lett.* **54**, 1317 (1985).
- <sup>32</sup>E. Fawcett, R. Griessen, W. Joss, and W. Kress, in *Phonon States of Alloys, Electron States and Fermi Surfaces of Strained Elements*, Landolt-Börnstein, New Series, Group 3, Vol. 13b, edited by K.-H. Hellwege, and J. L. Olsen (Springer, New York, 1983), p. 1.
- <sup>33</sup>I. V. Svezhikarev and A. S. Panfilov, *Phys. Status. Solidi (b)* **63**, 11 (1974).
- <sup>34</sup>H. Fukuyama and K. Yosida, *Jpn. J. Appl. Phys.* **26**, L371 (1987).
- <sup>35</sup>M. Cyrot, *Solid State Commun.* **62**, 821 (1987).
- <sup>36</sup>B. K. Chakraverty, *J. Phys. Lett.* **40**, L99 (1979); *J. Phys. (Paris)* **42**, 1351 (1981).
- <sup>37</sup>P. W. Anderson and M. L. Cohen, in Ref. 24, p. 24.
- <sup>38</sup>T. M. Rice and L. Sneddon, *Phys. Rev. Lett.* **47**, 689 (1981).
- <sup>39</sup>A. S. Alexandrov and J. Ranninger, *Phys. Rev. B* **24**, 1164 (1981).
- <sup>40</sup>A. S. Alexandrov, J. Ranninger, and S. Robaskiewicz, *Phys. Rev. B* **33**, 4526 (1986).
- <sup>41</sup>K. Nasu, *Phys. Rev. B* **35**, 1749 (1987).
- <sup>42</sup>R. Micnas, J. Ranninger, and S. Robaskiewicz, *J. Magn. Magn. Mater.* **63** & **64**, 420 (1987).
- <sup>43</sup>L. C. Bourne, M. F. Crommie, A. Zettl, H. C. zur Loye, S. W. Keller, K. L. Leary, A. M. Stacy, K. J. Chang, M. L. Cohen, and D. E. Morris, *Phys. Rev. Lett.* **58**, 2337 (1987).
- <sup>44</sup>B. Batlogg, R. J. Cava, A. Jayaraman, R. B. van Dover, G. A. Kourouklis, S. Sunshine, D. W. Murphy, L. W. Rupp, H. S. Chen, A. White, K. T. Short, A. M. Muijsce, and E. A. Rietman, *Phys. Rev. Lett.* **58**, 2333 (1987).